53/63S281/A

Advanced Micro Devices

High Performance 256x8 PROM TiW PROM Family

FEATURES/BENEFITS

- · 28-ns maximum access time
- Reliable titanium-tungsten fuses (TiW) guarantee greater than 98% programming yields
- · Low-voltage generic programming
- · PNP inputs for low input current
- Three-state outputs

APPLICATIONS

- · Microprogram control store
- Microprocessor program store
- Look-up table
- Character generator
- Code converter
- Programmable Logic Element (PLE™) with 8 Inputs, 8 Outputs, and 256 product terms

GENERAL DESCRIPTION

The 53/63S281/A are 256x8 bipolar PROMs featuring low input current PNP inputs, full Schottky clamping, and three-state outputs. The titanium-tungsten fuses store a logical low and are programmed to the high state. Special on-chip circuitry and extra fuses provide preprogramming testing which assures high programming yields and high reliability.

The 63 series is specified for operation over the commercial temperature and voltage range. The 53 series is specified for the military ranges.

PROGRAMMING

The 53/63S281/A PROMs are programmed with the same programming algorithm as all other Advanced

Micro Devices generic TiW PROMs. For details contact the factory.

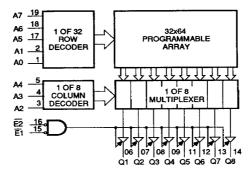
SELECTION GUIDE

Memory			Package			Part Number		
Size	Organization	Output	Pins	Туре	Performance	0°C to +75°C	-55°C to +125°C	
32K	4096x8	TS	24 (28)	CD 024 PD 024 CFM 024 PL 028 CL 028	Standard	63S3281	53S3281	
					Enhanced	63S3281A	53S3281A	
					Super Speed	_	53S3281B	

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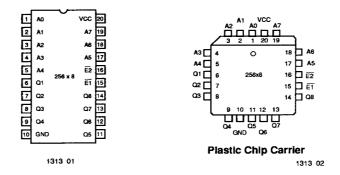
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BLOCK DIAGRAM DIP Pinout



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PIN CONFIGURATIONS



Note: LCC pinout identical to PLCC.

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ABSOLUTE MAXIMUM RATINGS

		Programming
Supply voltage Vcc	0.5 V to 7 V	12 V
	1.5 V to 7 V	
Input current	30 mA to +5 mA	
Off-state output voltage	je0.5 V to 5.5 V	12 V
Storage temperature.	65°C to +150°C	

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods of time may affect reliability. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

Operating Conditions

		Military†			Commercial			11-14
Symbol	Parameter	Min.	Nom.	Max.	Min.	Nom.	Max.	Unit
V _{cc}	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
T _A	Operating temperature*	-55		125	0		75	° C

^{*} This is defined as the instant-on case temperature.

DC Electrical Characteristics Over Operating Conditions. For APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted.

Symbol	Parameter	Test Conditions		Min.	Typ.†	Max	Unit		
V _{IL}	Low-level input voltage**							0.8	٧
V _{IH}	High-level input voltage**					2			٧
V _{IC}	Input clamp voltage	V _{cc} = MIN				-1.5	٧		
I _{IL}	Low-level input current	V _{cc} = MAX V _t = 0.4 V				-0.25	mA		
I _{IH}	High-level input current	V _{cc} = MAX	V _I = V _{CC} MAX				40	μΑ	
			Com		Com			0.45	v
V _{ol}	Low-level output voltage	V _{cc} = MIN	IN I _{OL} = 16 mA	Mil			0.5	Ľ	
			Com	I _{OH} = −3.2 mA					
V _{oн}	High-level output voltage	V _{cc} = MIN	Mil	I _{oh}	= −2 mA	2.4			\ \
l _{ozL}			V _o = 0.4 V					-4 0	
l _{ozh}	Off-state output current	V _{CC} = MAX	V _o = 2.4 V					40	μΑ
l _{os}	Output short-circuit current*	V _{oc} = 5 V V _o = 0 V			20		-90	mA	
Icc	Supply current	V _{cc} = MAX. All inputs grounded. All outputs open.					90	140	mA

Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second.

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[†] Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

^{**} V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

Switching Characteristics Over Operating Conditions (See standard test load). For APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted.^{††}

Operating Conditions	Device Type	t _{AA} (I Address Ac	ns) cess Time	t _{ea} ANI Enable Ad Recove	Unit	
		Typ.†	Max.	Тур.†	Max.	
	63S281A	21	28	18	25	- ns
Commercial	63S281	21	45	18	25	
	53S281A	21	40	18	30	
Military	53\$281	21	50	18	30	

[†] Typicals at 5.0 V $V_{\rm cc}$ and 25°C $T_{\rm A}$.

^{††} Subgroups 7 and 8 apply to Functional tests.

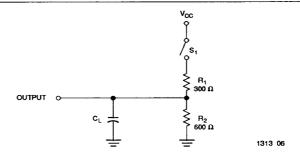


Figure 3. Switching Test Load

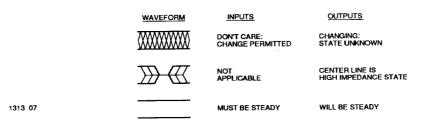
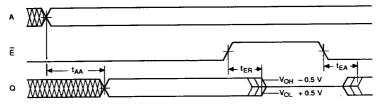


Figure 4. Definition of Timing Diagram



NOTES: 1. INPUT PULSE AMPLITUDE 0 V TO 3.0 V.

- 2. INPUT RISE AND FALL TIMES 2-5 ns FROM 0.8 V TO 2.0 V.
- 3. INPUT ACCESS MEASURED AT THE 1.5 V LEVEL.
- 4. t_{AA} is tested with switch s $_1$ closed. $C_L = 30 \, \mathrm{pF}$ and measured at 1.5 V output level.
- 5 1EA IS MEASURED AT THE 1.5 V OUTPUT LEVEL WITH C_L = 30 pF. S₁ IS OPEN FOR HIGH IMPEDANCE TO *1* TEST, AND CLOSED FOR HIGH IMPEDANCE TO *0" TEST.

 $t_{\rm ER}$ is tested with C $_{\rm L}$ = 5 pf. S, is open for "1" to high impedance test, measured at $v_{\rm OH}$ – 0.5 v output level; S 1 is closed for "0" to high impedance test, measured at $v_{\rm OL}$ + 0.5 v output level.

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Figure 5. Definition of Waveforms